SBS 1.1-COMPLIANT GAS GAUGE ENABLED WITH IMPEDANCE TRACK™ TECHNOLOGY FOR USE WITH THE bq29330

Check for Samples: bq20z40-R1

FEATURES

- **Next Generation Patented Impedance Track™ Technology Accurately Measures Available Charge in Li-Ion and Li-Polymer Batteries**
  - **Better Than 1% Error Over the Lifetime of the Battery**
- **Supports the Smart Battery Specification SBS V1.1**
- **Flexible Configuration for 2-Series, 3-Series, and 4-Series Cell Li-Ion and Li-Polymer Batteries**
- **Powerful 8-Bit RISC CPU With Ultralow Power Modes**
- **Full Array of Programmable Protection Features**
  - **Voltage, Current, and Temperature**
- **Complies with JEITA Guidelines**
- **Added Flexibility to Handle More Complex Charging Profiles**
- **Lifetime Data Logging**
- **Supports SHA-1 Authentication**
- **Available in 20-Pin TSSOP (PW) and 32-Pin QFN (RSM) Packages**

APPLICATIONS

- **Notebook PCs**
- **Medical and Test Equipment**
- **Portable Instrumentation**

DESCRIPTION

The bq20z40-R1 SBS-compliant gas gauge and protection IC, incorporating patented Impedance Track™ technology, is designed for battery-pack or in-system installation. The bq20z40-R1 measures and maintains an accurate record of available charge in Li-Ion or Li-Polymer batteries using its integrated high-performance analog peripherals. The bq20z40-R1 monitors capacity change, battery impedance, open-circuit voltage, and other critical parameters of the battery pack, and reports the information to the system host controller over a serial-communication bus. It is designed to work with the bq29330 analog front-end (AFE) protection IC to maximize functionality and safety, while minimizing external component count and cost in smart battery circuits.

The Impedance Track™ technology continuously analyzes the battery impedance, resulting in superior gas-gauging accuracy. This enables the remaining capacity to be calculated with discharge rate, temperature, and cell aging, which are all accounted for during each stage of every cycle.

Table 1. AVAILABLE OPTIONS

T_A	PACKAGE			
	20-PIN TSSOP (PW) Tube	**20-PIN TSSOP (PW) Tape & Reel**	**32-PIN QFN (RSM) Tube**	**32-PIN QFN (RSM) Tape & Reel**
–40°C to 85°C	bq20z40-R1PW(1)	bq20z40-R1PWR(2)	bq20z40-R1RSM(1)	bq20z40-R1RSMR(2)

(1) A single tube quantity is 50 units.
(2) A single reel quantity is 2000 units.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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THERMAL INFORMATION

THERMAL METRIC(1)		bq20z40-R1		UNITS
		TSSOP (PW)	QFN (RSM)	
		20 PINS	32 PINS	
$\theta_{JA, High K}$	Junction-to-ambient thermal resistance(2)	89.5	37.4	°C/W
$\theta_{JC (top)}$	Junction-to-case(top) thermal resistance(3)	23.4	30.6	
θ_{JB}	Junction-to-board thermal resistance(4)	41.0	7.7	
ψ_{JT}	Junction-to-top characterization parameter(5)	0.9	0.4	
ψ_{JB}	Junction-to-board characterization parameter(6)	40.5	7.5	
$\theta_{JC (bottom)}$	Junction-to-case(bottom) thermal resistance(7)	n/a	2.6	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.
(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
(5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
(6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SYSTEM PARTITIONING DIAGRAM

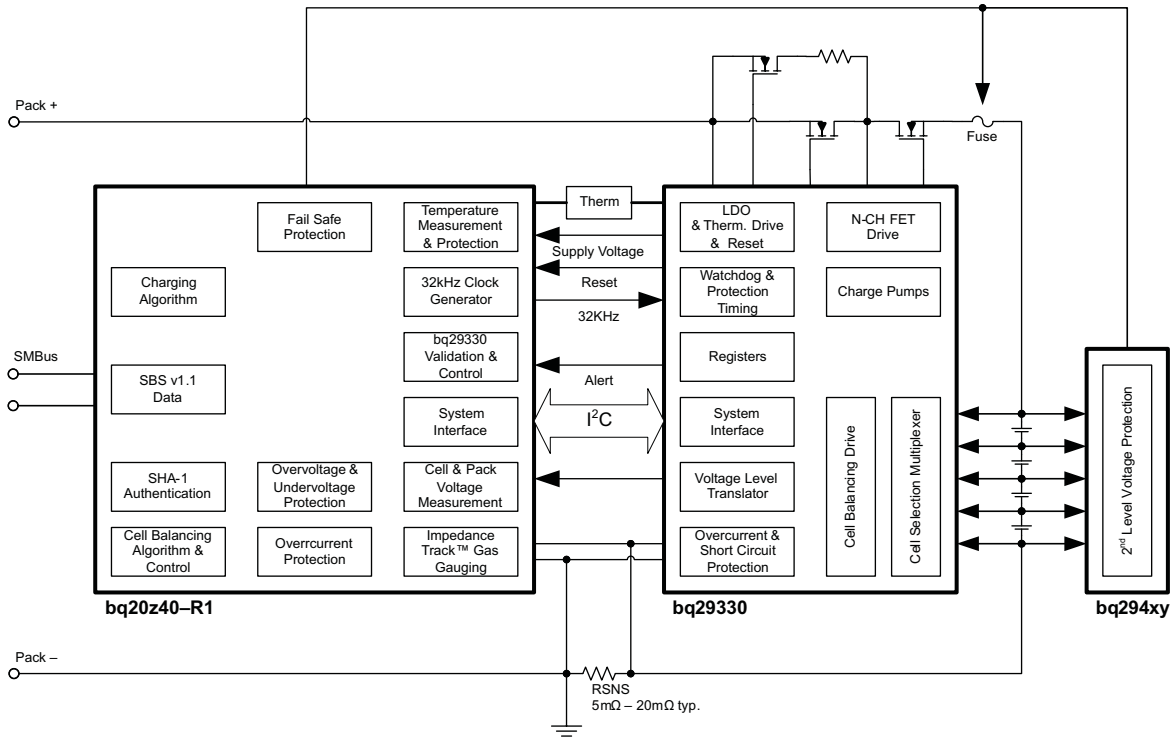
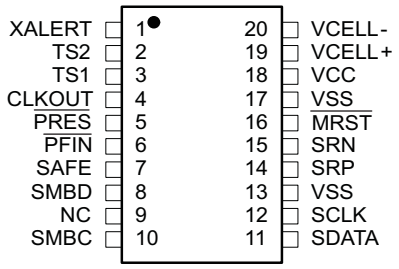


Figure 1. System Partitioning

TSSOP (PW) PIN FUNCTIONS

TSSOP (PW)
(TOP VIEW)



TSSOP (PW) PIN CONFIGURATIONS

PIN		I/O (1)	DESCRIPTION
NO.	NAME		
1	XALERT	I	Input from bq29330 XALERT output
2	TS2	I	2nd Thermistor voltage input connection to monitor temperature
3	TS1	I	1st Thermistor voltage input connection to monitor temperature
4	CLKOUT	O	32.768-kHz output for the bq29330. This pin should be directly connected to the AFE.

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

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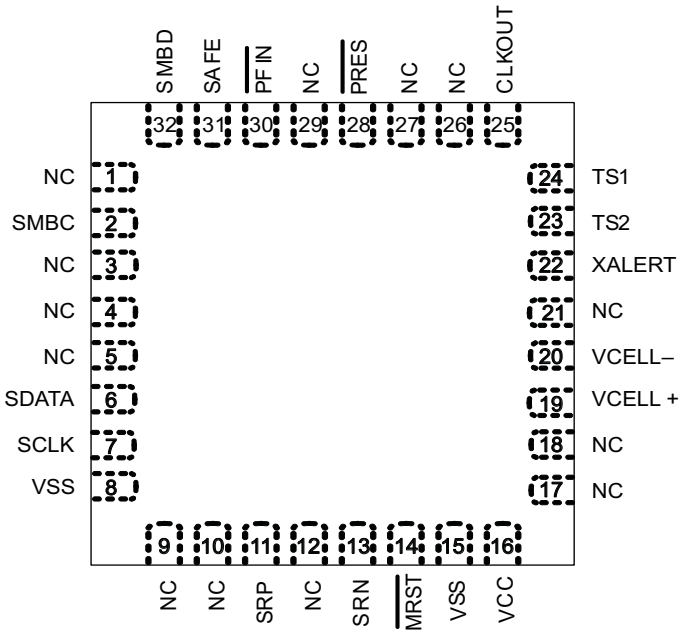
TSSOP (PW) PIN CONFIGURATIONS (continued)

PIN		I/O(1)	DESCRIPTION
NO.	NAME		
5	$\overline{\text{PRES}}$	I	Active low input to sense system insertion. Typically requires additional ESD protection.
6	$\overline{\text{PFIN}}$	I	Active low input to detect secondary protector output status, and to allow the bq20z40-R1 to report the status of the 2nd level protection output
7	SAFE	O	Active high output to enforce additional level of safety protection; e.g., fuse blow
8	SMBD	I/OD	SMBus data open-drain bidirectional pin used to transfer address and data to and from the bq20z40-R1
9	NC	—	Not used—leave floating
10	SMBC	I/OD	SMBus clock open-drain bidirectional pin used to clock the data transfer to and from the bq20z40-R1
11	SDATA	I/O	Data transfer to and from bq29330
12	SCLK	I/O	Communication clock to the bq29330
13	VSS	—	Connected I/O pin to VSS
14	SRP	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
15	SRN	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
16	$\overline{\text{MRST}}$	I	Master reset input that forces the device into reset when held low. Must be held high for normal operation
17	VSS	P	Negative Supply Voltage
18	VCC	P	Positive Supply Voltage
19	VCELL+	I	Input from bq29330 used to read a scaled value of individual cell voltages
20	VCELL–	I	Input from bq29330 used to read a scaled value of individual cell voltages

QFN (RSM) PIN FUNCTIONS

QFN (RSM)
(TOP VIEW)



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QFN (RSM) PIN CONFIGURATIONS

PIN		I/O(1)	DESCRIPTION
NO.	NAME		
1	NC	—	Not used—leave floating
2	SMBC	I/OD	SMBus clock open-drain bidirectional pin used to clock the data transfer to and from the bq20z40-R1
3	NC	—	Not used—leave floating
4	NC	—	Not used—leave floating
5	NC	—	Not used—leave floating
6	SDATA	I/O	Data transfer to and from bq29330
7	SCLK	I/O	Communication clock to the bq29330
8	VSS	—	Connected I/O pin to VSS
9	NC	—	Not used—leave floating
10	NC	—	Not used—leave floating
11	SRP	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
12	NC	—	Not used—leave floating
13	SRN	IA	Connections for a small-value sense resistor to monitor the battery charge- and discharge-current flow
14	$\overline{\text{MRST}}$	I	Master reset input that forces the device into reset when held low. Must be held high for normal operation
15	VSS	P	Negative Supply Voltage
16	VCC	P	Positive Supply Voltage
17	NC	—	Not used—leave floating
18	NC	—	Not used—leave floating
19	VCELL+	I	Input from bq29330 used to read a scaled value of individual cell voltages
20	VCELL–	I	Input from bq29330 used to read a scaled value of individual cell voltages
21	NC	—	Not used—leave floating
22	XALERT	I	Input from bq29330 XALERT output
23	TS2	I	Thermistor 2 input
24	TS1	I	Thermistor 1 input
25	CLKOUT	O	32.768-kHz output to the bq29330. This pin should be directly connected to the bq29330 AFE.
26	NC	—	Not used—leave floating
27	NC	—	Not used—leave floating
28	$\overline{\text{PRES}}$	I	Active low input to sense system insertion. This typically requires additional ESD protection.
29	NC	—	Not used—leave floating
30	$\overline{\text{PFIN}}$	I	Active low input to detect secondary protector output status, and to allow the bq20z40-R1 to report the status of the 2nd level protection output
31	SAFE	O	Active high output to enforce additional level of safety protection; e.g., fuse blow
32	SMBD	I/OD	SMBus data open-drain bidirectional pin used to transfer address and data to and from the bq20z40-R1

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

PARAMETER		RANGE
V_{CC} relative to V_{SS}	Supply voltage range	–0.3 V to 2.75 V
$V_{(IOD)}$ relative to V_{SS}	Open-drain I/O pins	–0.3 V to 6 V
V_I relative to V_{SS}	Input voltage range to all other pins	–0.3 V to V_{CC} + 0.3 V
T_A	Operating free-air temperature range	–40°C to 85°C
T_{stg}	Storage temperature range	–65°C to 150°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage		2.4	2.5	2.6	V
I_{CC}	Operating mode current	No flash programming		400(1)		µA
		bq20z40-R1 + bq29330		475		
$I_{(SLP)}$	Low-power storage mode current	Sleep mode		8(1)		µA
		bq20z40-R1 + bq29330		51		
$I_{(SD)}$	Shutdown Mode Current	Shutdown mode		0.1(1)		µA
		bq20z40-R1 + bq29330		0.2		
V_{OL}	Output voltage low SMBC, SMBD, SDATA, SCLK, SAFE	I_{OL} = 0.5 mA			0.4	V
V_{OH}	Output high voltage, SMBC, SMBD, SDATA, SCLK, SAFE	I_{OH} = –1 mA	V_{CC} –0.5			V
V_{IL}	Input voltage low SMBC, SMBD, SDATA, SCLK, XALERT, $\overline{PRES}$, $\overline{PFIN}$		–0.3		0.8	V
V_{IH}	Input voltage high SMBC, SMBD, SDATA, SCLK, XALERT, $\overline{PRES}$, $\overline{PFIN}$		2		6	V
C_{IN}	Input capacitance			5		pF
$V_{(AI1)}$	Input voltage range VCELL+, VCELL–,TS1, TS2		–0.2		0.8 × V_{CC}	V
$V_{(AI2)}$	Input voltage range SRN, SRP		–0.20		0.20	
$Z_{(AI2)}$	Input impedance VCELL+, VCELL-, TS1, TS2	0 V–1 V	8			MΩ
$Z_{(AI1)}$	Input impedance SRN, SRP	0 V–1 V	2.5			MΩ

(1) This value does not include the bq29330.

POWER-ON RESET

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IT-}	Negative-going voltage input		1.7	1.8	1.9	V
V_{HYS}	Power-on reset hysteresis		50	125	200	mV

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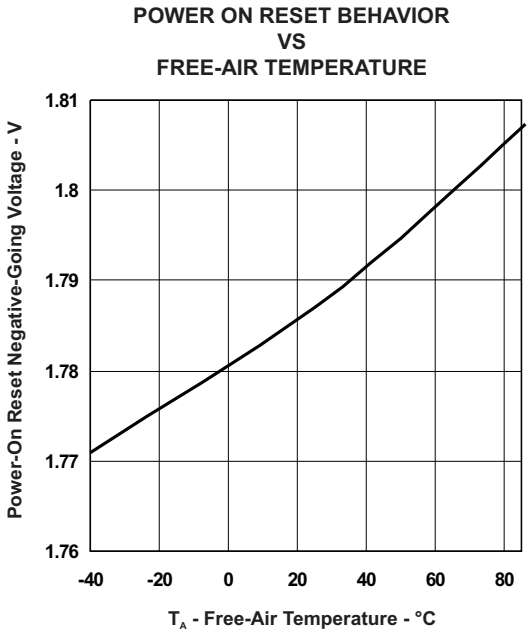

INTEGRATING ADC (Coulomb Counter) CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(SR)}$	Input voltage range, $V_{(SRN)}$ and $V_{(SRP)}$	$V_{(SR)}$ = V(SRN) – V(SRP)	–0.2		0.2	V
$V_{(SROS)}$	Input offset			10		µV
INL	Integral nonlinearity error			0.007 %	0.034 %	

OSCILLATOR

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
HIGH FREQUENCY OSCILLATOR					
$f_{(OSC)}$ Operating Frequency				4.194	MHz
$f_{(EIO)}$ Frequency Error(1) (2)		–3%	0.25%	3%	
	T_A = 20°C to 70°C	–2%	0.25%	2%	
$t_{(SXO)}$ Start-up Time(3)			2.5	5	ms
LOW FREQUENCY OSCILLATOR					
$f_{(LOSC)}$ Operating Frequency		32.768			KHz
$f_{(LEIO)}$ Frequency Error(2) (4)		–2.5%	0.25%	2.5%	
	T_A = 20°C to 70°C	–1.5%	0.25%	1.5%	
$t_{(LSXO)}$ Start-up time (5)				500	µs

(1) The frequency error is measured from 4.194 MHz.
(2) The frequency drift is included and measured from the trimmed frequency at V_{CC} = 2.5 V, T_A = 25°C.
(3) The start-up time is defined as the time it takes for the oscillator output frequency to be within 1 % of the specified frequency.
(4) The frequency error is measured from 32.768 kHz.
(5) The start-up time is defined as the time it takes for the oscillator output frequency to be ± 3%.

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DATA FLASH MEMORY CHARACTERISTICS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{DR}	Data retention	See (1)	10			Years
	Flash programming write-cycles	See (1)	20,000			Cycles
$t_{(WORDPROG)}$	Word programming time	See (1)			2	ms
$I_{(DDdPROG)}$	Flash-write supply current	See (1)		5	10	mA

(1) Specified by design. Not production tested.

SMBus TIMING SPECIFICATIONS

V_{CC} = 2.4 V to 2.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{SMB}	SMBus operating frequency	Slave mode, SMBC 50% duty cycle	10		100	kHz
f_{MAS}	SMBus master clock frequency	Master mode, no clock low slave extend		51.2		
t_{BUF}	Bus free time between start and stop		4.7			µs
$t_{HD:STA}$	Hold time after (repeated) start		4			
$t_{SU:STA}$	Repeated start setup time		4.7			
$t_{SU:STO}$	Stop setup time		4			
$t_{HD:DAT}$	Data hold time	Receive mode	0			ns
		Transmit mode	300			
$t_{SU:DAT}$	Data setup time		250			
$t_{TIMEOUT}$	Error signal/detect	See (1)	25		35	ms
t_{LOW}	Clock low period		4.7			µs
t_{HIGH}	Clock high period	See (2)	4		50	
$t_{LOW:SEXT}$	Cumulative clock low slave extend time	See (3)			25	ms
$t_{LOW:MEXT}$	Cumulative clock low master extend time	See (4)			10	
t_F	Clock/data fall time	(V_{IL}MAX – 0.15 V) to (V_{IH}MIN + 0.15 V)			300	ns
t_R	Clock/data rise time	0.9 V_{CC} to (V_{IL}MAX – 0.15 V)			1000	

(1) The bq20z40-R1 times out when any clock low exceeds $t_{TIMEOUT}$.
(2) $t_{HIGH:MAX}$ is minimum bus idle time. SMBC = 1 for t > 50 µs causes reset of any transaction involving the bq20z40-R1 that is in progress.
(3) $t_{LOW:SEXT}$ is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop.
(4) $t_{LOW:MEXT}$ is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop.

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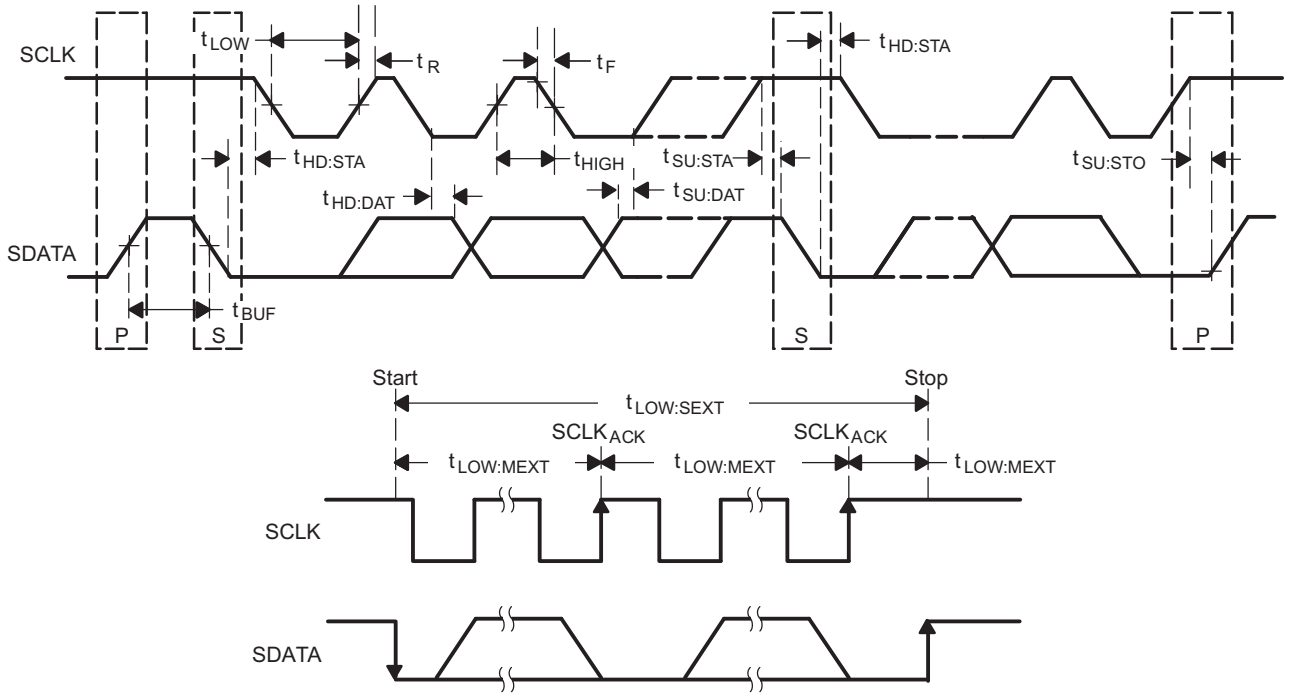
SMBus TIMING DIAGRAM



FEATURE SET

Primary (1st Level) Safety Features

The bq20z40-R1 supports a wide range of battery and system protection features that can easily be configured. The primary safety features include:

- Cell over/undervoltage protection
- Charge and discharge overcurrent
- Short Circuit
- Charge and discharge overtemperature with independent alarms and thresholds for each thermistor
- AFE Watchdog

Secondary (2nd Level) Safety Features

The secondary safety features of the bq20z40-R1 can be used to indicate more serious faults via the SAFE (pin 7). This pin can be used to blow an in-line fuse to permanently disable the battery pack from charging or discharging. The secondary safety protection features include:

- Safety overvoltage
- Safety undervoltage
- Safety overcurrent in charge and discharge
- Safety overtemperature in charge and discharge with independent alarms and thresholds for each thermistor
- Charge FET and 0 Volt Charge FET fault
- Discharge FET fault
- Cell imbalance detection (active and at rest)
- Open thermistor detection
- AFE communication fault

Charge Control Features

The bq20z40-R1 charge control features include:

- Supports JEITA temperature ranges. Reports charging voltage and charging current according to the active temperature range.
- Handles more complex charging profiles. Allows for splitting the standard temperature range into two sub-ranges and allows for varying the charging current according to the cell voltage.
- Reports the appropriate charging current needed for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger using SMBus broadcasts.
- Determines the chemical state of charge of each battery cell using Impedance Track™ and can reduce the charge difference of the battery cells in fully charged state of the battery pack gradually using cell balancing algorithm during charging. This prevents fully charged cells from overcharging and causing excessive degradation and also increases the usable pack energy by preventing premature charge termination
- Supports pre-charging/zero-volt charging
- Supports charge inhibit and charge suspend if battery pack temperature is out of temperature range
- Reports charging fault and also indicate charge status via charge and discharge alarms.

Gas Gauging

The bq20z40-R1 uses the Impedance Track Technology to measure and calculate the available charge in battery cells. The achievable accuracy is better than 1% error over the lifetime of the battery and there is no full charge discharge learning cycle required.

See *Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm* application note (SLUA364) for further details.

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Lifetime Data Logging Features

The bq20z40-R1 offers lifetime data logging, where important measurements are stored for warranty and analysis purposes. The data monitored include:

- Lifetime maximum temperature
- Lifetime minimum temperature
- Lifetime maximum battery cell voltage
- Lifetime minimum battery cell voltage
- Lifetime maximum battery pack voltage
- Lifetime minimum battery pack voltage
- Lifetime maximum charge current
- Lifetime maximum discharge current
- Lifetime maximum charge power
- Lifetime maximum discharge power
- Lifetime maximum average discharge current
- Lifetime maximum average discharge power
- Lifetime average temperature

Authentication

The bq20z40-R1 supports authentication by the host using SHA-1.

Power Modes

The bq20z40-R1 supports three power modes to reduce power consumption:

- In Normal Mode, the bq20z40-R1 performs measurements, calculations, protection decisions and data updates in 1-s intervals. Between these intervals, the bq20z40-R1 is in a reduced power stage.
- In Sleep Mode, the bq20z40-R1 performs measurements, calculations, protection decisions, and data updates in adjustable time intervals. Between these intervals, the bq20z40-R1 is in a reduced power stage. The bq20z40-R1 has a wake function that enables exit from Sleep mode when current flow or failure is detected.
- In Shutdown Mode, the bq20z40-R1 is completely disabled.

CONFIGURATION

Oscillator Function

The bq20z40-R1 fully integrates the system and processor oscillators and, therefore, requires no pins or components for this feature.

System Present Operation

The bq20z40-R1 periodically verifies the $\overline{\text{PRES}}$ pin and detects that the battery is present in the system via a low state on a $\overline{\text{PRES}}$ input. When this occurs, bq20z40-R1 enters normal operating mode. When the pack is removed from the system and the $\overline{\text{PRES}}$ input is high, the bq20z40-R1 enters the battery-removed state, disabling the charge, discharge, and ZVCHG FETs. The $\overline{\text{PRES}}$ input is ignored and can be left floating when non-removal mode is set in the data flash.

BATTERY PARAMETER MEASUREMENTS

The bq20z40-R1 uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement, and a second delta-sigma ADC for individual cell and battery voltage and temperature measurement.

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Charge and Discharge Counting

The integrating delta-sigma ADC measures the charge/discharge flow of the battery by measuring the voltage drop across a small-value sense resistor between the SRP and SRN pins. The integrating ADC measures bipolar signals from –0.25 V to 0.25 V. The bq20z40-R1 detects charge activity when $V_{SR} = V_{(SRP)} – V_{(SRN)}$ is positive, and discharge activity when $V_{SR} = V_{(SRP)} – V_{(SRN)}$ is negative. The bq20z40-R1 continuously integrates the signal over time, using an internal counter. The fundamental rate of the counter is 0.65 nVh.

Voltage

The bq20z40-R1 updates the individual series cell voltages through the bq29330 at 1-s intervals. The bq20z40-R1 configures the bq29330 to connect the selected cell, cell offset, or bq29330 VREF to the CELL pin of the bq29330, which is required to be connected to VIN of the bq20z40-R1. The internal ADC of the bq20z40-R1 measures the voltage, scales it, and calibrates itself appropriately. This data is also used to calculate the impedance of the cell for the Impedance Track gas-gauging.

Current

The bq20z40-R1 uses the SRP and SRN inputs to measure and calculate the battery charge and discharge current using a 5 mΩ to 20 mΩ typ. sense resistor.

Wake Function

The bq20z40-R1 can exit sleep mode, if enabled, by the presence of a programmable level of current signal across SRP and SRN.

Auto Calibration

The bq20z40-R1 provides an auto-calibration feature to cancel the voltage offset error across SRP and SRN for maximum charge measurement accuracy. The bq20z40-R1 performs auto-calibration when the SMBus lines stay low continuously for a minimum of a programmable amount of time.

Temperature

The bq20z40-R1 has an internal temperature sensor and inputs for two external temperature sensors, TS1 and TS2, used in conjunction with two identical NTC thermistors (default are Semitec 103AT) to sense the battery environmental temperature. The bq20z40-R1 can be configured to use one internal or up to two external temperature sensors.

COMMUNICATIONS

The bq20z40-R1 uses SMBus v1.1 with Master Mode and package error checking (PEC) options per the SBS specification.

SMBus On and Off State

The bq20z40-R1 detects an SMBus off state when SMBC and SMBD are logic-low for ≥ 2 seconds. Clearing this state requires either SMBC or SMBD to transition high. Within 1 ms, the communication bus is available.

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SBS Commands

Table 2. SBS COMMANDS

SBS Cmd	Mode	Name	Format	Size in Bytes	Min Value	Max Value	Default Value	Unit
0x00	R/W	ManufacturerAccess	hex	2	0x0000	0xffff	—	
0x01	R/W	RemainingCapacityAlarm	unsigned int	2	0	65535	300	mAh or 10 mWh
0x02	R/W	RemainingTimeAlarm	unsigned int	2	0	65535	10	min
0x03	R/W	BatteryMode	hex	2	0x0000	0xe383	—	
0x04	R/W	AtRate	signed int	2	–32768	32767	—	mA or 10 mW
0x05	R	AtRateTimeToFull	unsigned int	2	0	65534	—	min
0x06	R	AtRateTimeToEmpty	unsigned int	2	0	65534	—	min
0x07	R	AtRateOK	unsigned int	2	0	65535	—	
0x08	R	Temperature	unsigned int	2	0	65535	—	0.1°K
0x09	R	Voltage	unsigned int	2	0	65535	—	mV
0x0a	R	Current	signed int	2	–32768	32767	—	mA
0x0b	R	AverageCurrent	signed int	2	–32768	32767	—	mA
0x0c	R	MaxError	unsigned int	1	0	100	—	%
0x0d	R	RelativeStateOfCharge	unsigned int	1	0	100	—	%
0x0e	R	AbsoluteStateOfCharge	unsigned int	1	0	100+	—	%
0x0f	R/W	RemainingCapacity	unsigned int	2	0	65535	—	mAh or 10 mWh
0x10	R	FullChargeCapacity	unsigned int	2	0	65535	—	mAh or 10 mWh
0x11	R	RunTimeToEmpty	unsigned int	2	0	65534	—	min
0x12	R	AverageTimeToEmpty	unsigned int	2	0	65534	—	min
0x13	R	AverageTimeToFull	unsigned int	2	0	65534	—	min
0x14	R	ChargingCurrent	unsigned int	2	0	65534	—	mA
0x15	R	ChargingVoltage	unsigned int	2	0	65534	—	mV
0x16	R	BatteryStatus	hex	2	0x0000	0xdbff	—	
0x17	R/W	CycleCount	unsigned int	2	0	65535	—	
0x18	R/W	DesignCapacity	unsigned int	2	0	65535	4400	mAh or 10 mWh
0x19	R/W	DesignVoltage	unsigned int	2	0	65535	14400	mV
0x1a	R/W	SpecificationInfo	hex	2	0x0000	0xffff	0x0031	
0x1b	R/W	ManufactureDate	unsigned int	2	—	—	01-Jan-1980	—
0x1c	R/W	SerialNumber	hex	2	0x0000	0xffff	0x0001	
0x20	R/W	ManufacturerName	String	20+1	—	—	Texas Inst.	—
0x21	R/W	DeviceName	String	20+1	—	—	bq20z40-R1	—
0x22	R/W	DeviceChemistry	String	4+1	—	—	LION	—
0x23	R/W	ManufacturerData	String	14+1	—	—	—	—
0x2f	R/W	Authenticate	String	20+1	—	—	—	—
0x3c	R	CellVoltage4	unsigned int	2	0	65535	—	mV
0x3d	R	CellVoltage3	unsigned int	2	0	65535	—	mV
0x3e	R	CellVoltage2	unsigned int	2	0	65535	—	mV
0x3f	R	CellVoltage1	unsigned int	2	0	65535	—	mV

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Table 3. EXTENDED SBS COMMANDS

SBS Cmd	Mode	Name	Format	Size in Bytes	Min Value	Max Value	Default Value	Unit
0x45	R	AFEData	String	11+1	—	—	—	—
0x46	R/W	FETControl	hex	2	0x00	0xff	—	—
0x4f	R	StateOfHealth	hex	2	0x0000	0xffff	—	%
0x51	R	SafetyStatus	hex	2	0x0000	0xffff	—	—
0x53	R	PFStatus	hex	2	0x0000	0xffff	—	—
0x54	R	OperationStatus	hex	2	0x0000	0xffff	—	—
0x55	R	ChargingStatus	hex	2	0x0000	0xffff	—	—
0x57	R	ResetData	hex	2	0x0000	0xffff	—	—
0x58	R	WDResetData	unsigned int	2	0	65535	—	—
0x5a	R	PackVoltage	unsigned int	2	0	65535	—	mV
0x5d	R	AverageVoltage	unsigned int	2	0	65535	—	mV
0x5e	R	TS1Temperature	integer	2	–400	1200	—	0.1°C
0x5f	R	TS2Temperature	integer	2	–400	1200	—	0.1°C
0x60	R/W	UnSealKey	hex	4	0x00000000	0xffffffff	—	—
0x61	R/W	FullAccessKey	hex	4	0x00000000	0xffffffff	—	—
0x62	R/W	PFKey	hex	4	0x00000000	0xffffffff	—	—
0x63	R/W	AuthenKey3	hex	4	0x00000000	0xffffffff	—	—
0x64	R/W	AuthenKey2	hex	4	0x00000000	0xffffffff	—	—
0x65	R/W	AuthenKey1	hex	4	0x00000000	0xffffffff	—	—
0x66	R/W	AuthenKey0	hex	4	0x00000000	0xffffffff	—	—
0x69	R	SafetyStatus2	hex	2	0x0000	0x0003	—	—
0x6b	R	PFStatus2	hex	2	0x0000	0x0003	—	—
0x6c	R/W	ManufBlock1	String	20	—	—	—	—
0x6d	R/W	ManufBlock2	String	20	—	—	—	—
0x6e	R/W	ManufBlock3	String	20	—	—	—	—
0x6f	R/W	ManufBlock4	String	20	—	—	—	—
0x70	R/W	ManufacturerInfo	String	31+1	—	—	—	—
0x71	R/W	SenseResistor	unsigned int	2	0	65535	—	µΩ
0x72	R	TempRange	hex	2	—	—	—	—
0x73	R	LifetimeData	String	32+1	—	—	—	—
0x77	R/W	DataFlashSubClassID	hex	2	0x0000	0xffff	—	—
0x78	R/W	DataFlashSubClassPage1	hex	32	—	—	—	—
0x79	R/W	DataFlashSubClassPage2	hex	32	—	—	—	—
0x7a	R/W	DataFlashSubClassPage3	hex	32	—	—	—	—
0x7b	R/W	DataFlashSubClassPage4	hex	32	—	—	—	—
0x7c	R/W	DataFlashSubClassPage5	hex	32	—	—	—	—
0x7d	R/W	DataFlashSubClassPage6	hex	32	—	—	—	—
0x7e	R/W	DataFlashSubClassPage7	hex	32	—	—	—	—
0x7f	R/W	DataFlashSubClassPage8	hex	32	—	—	—	—

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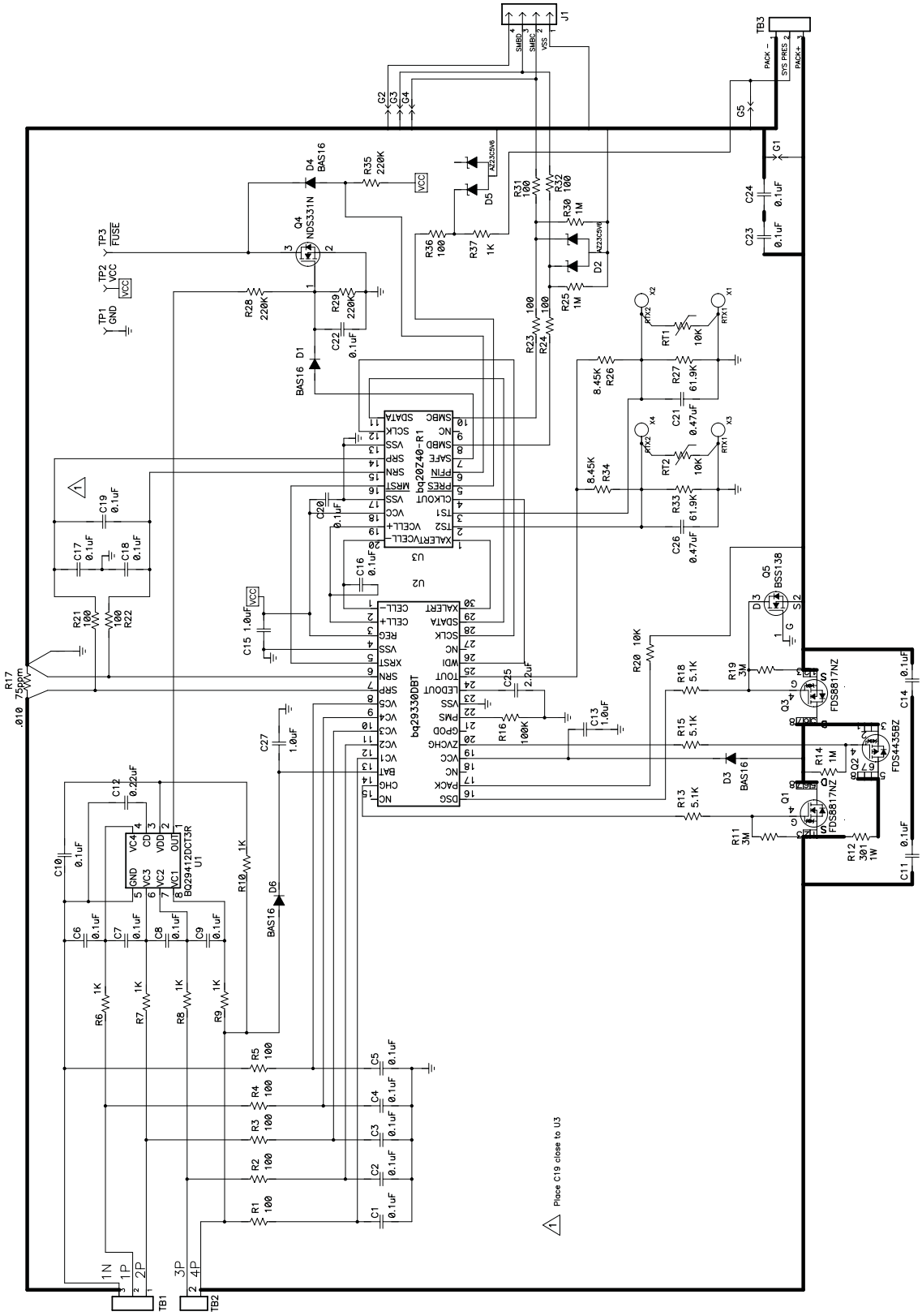
APPLICATION SCHEMATIC



REVISION HISTORY

Changes from Original (December 2009) to Revision A	Page
• Added the 32-pin QFN (RSM) package	1
• Added Shutdown Mode Current to the Electrical Characteristics Table	6

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
BQ20Z40PW-R1	NRND	Production	TSSOP (PW) | 20	70 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	20Z40
BQ20Z40PW-R1.A	NRND	Production	TSSOP (PW) | 20	70 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	20Z40
BQ20Z40PWR-R1	NRND	Production	TSSOP (PW) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	20Z40
BQ20Z40PWR-R1.A	NRND	Production	TSSOP (PW) | 20	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	20Z40

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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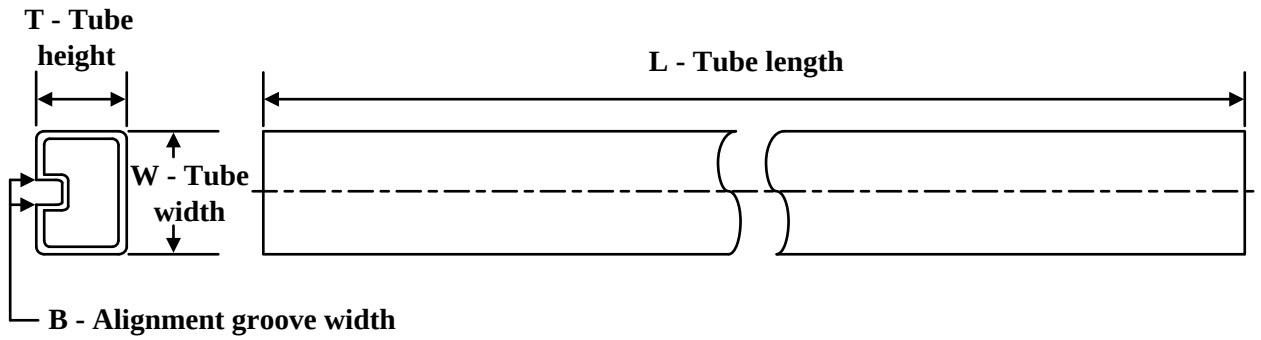
TUBE



*All dimensions are nominal

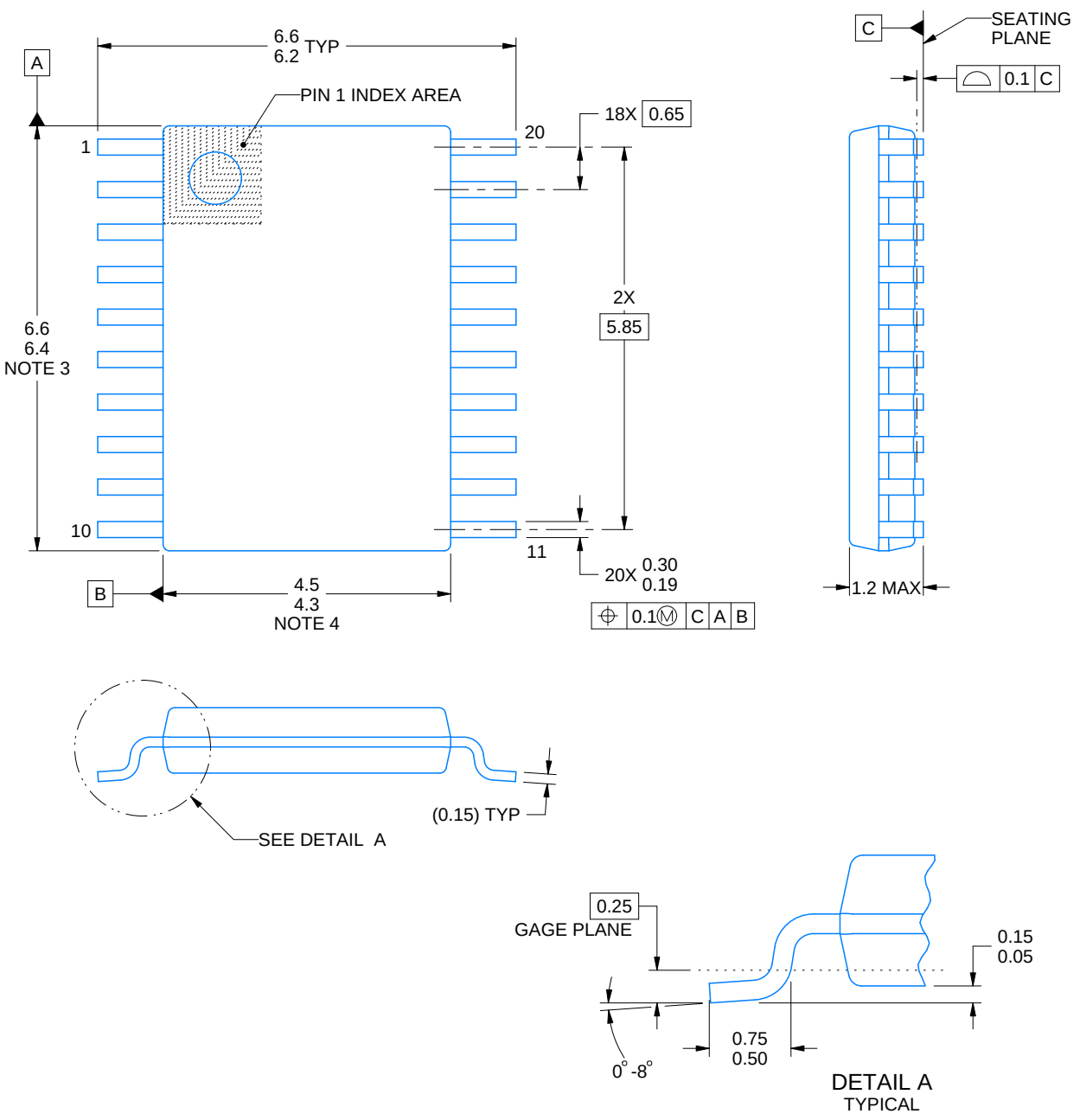
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
BQ20Z40PW-R1	PW	TSSOP	20	70	530	10.2	3600	3.5
BQ20Z40PW-R1.A	PW	TSSOP	20	70	530	10.2	3600	3.5

PACKAGE OUTLINE

PW0020A

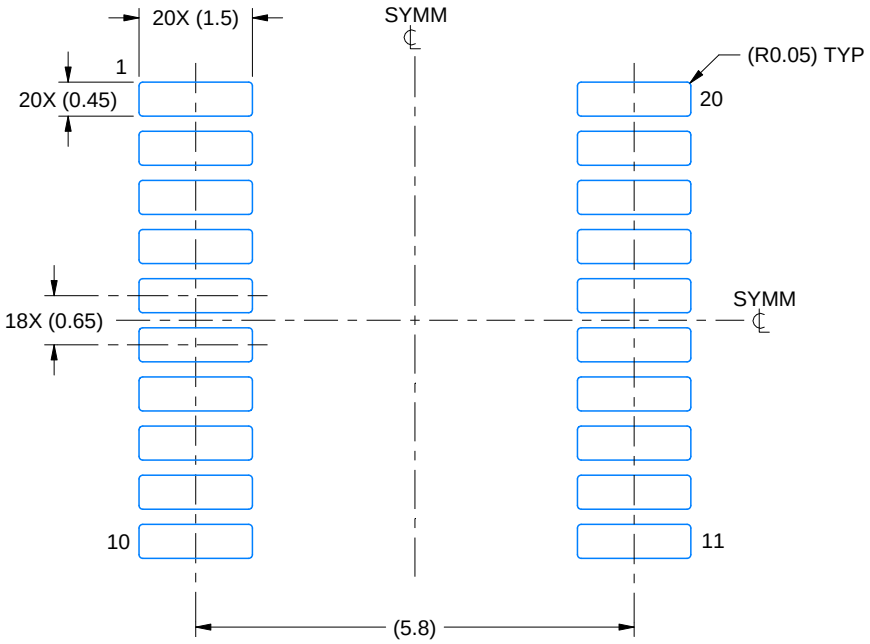
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



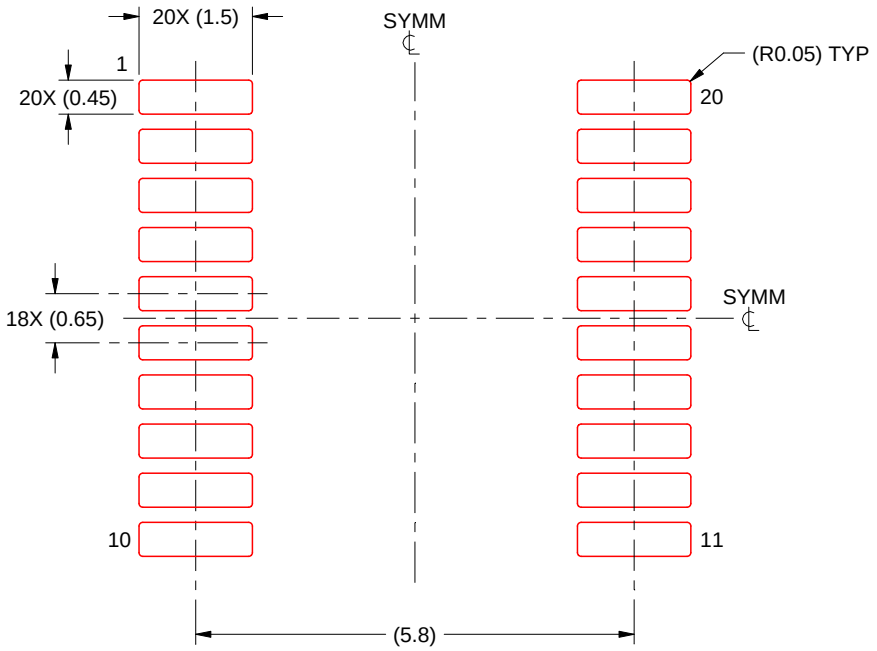
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

SOLDER MASK DETAILS

4220206/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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